

## Analog Signal Input Monaural, Filter Less 3.0W Class-D Amplifier

### FEATURES (Typical value, Ta=25°C)

- Supply voltage ( $R_L \geq 3.6\Omega$ ) 1.8V to 5.5V
- High Power ( $V^+ = 5V$ , THD+N=10%)
  - $R_L = 8\Omega$  1.7W
  - $R_L = 4\Omega$  3.0W
- Output LC Filterless Architecture
- Built-in Pop noise reduction (Turn on/Turn off)
- Analog Differential Input / PWM Output
- Low Supply Current ( $V^+ = 3.6V$ ) 2.7mA
  - Standby Current 1μA max.
- Protection
  - Short-Circuit
  - Thermal Shut Down
  - Under Voltage Lock Out (UVLO)
- Space Saving Package WCSP9

### DESCRIPTION

The NJU8759 is an analog signal input monaural filterless class-D power amplifier. Operating voltage from 1.8V to 5.5V single supply can be used with 2-cell batteries.

NJU8759 features Class-D operation with high output capability, is 1.7W output (8Ω load) and 3.0W output (4Ω load). The BTL output configuration can reduce the coupling capacitor. Furthermore, the output LC filterless architecture, which was not available in conventional class-D, reduces external parts and PCB size.

The NJU8759 operates from a single power supply of 1.8 V and 1 μA maximum standby current, and is ideal for small portable devices and portable audio devices, as well as alarm devices and security devices that require low power and high output.

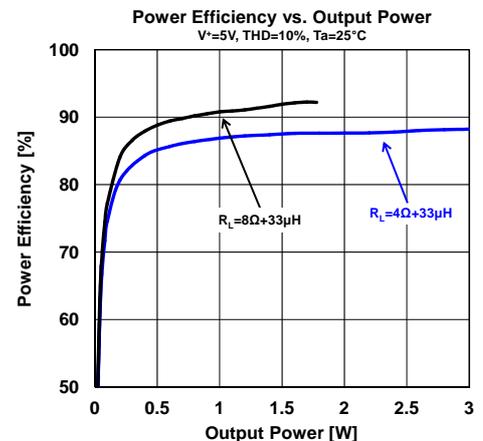
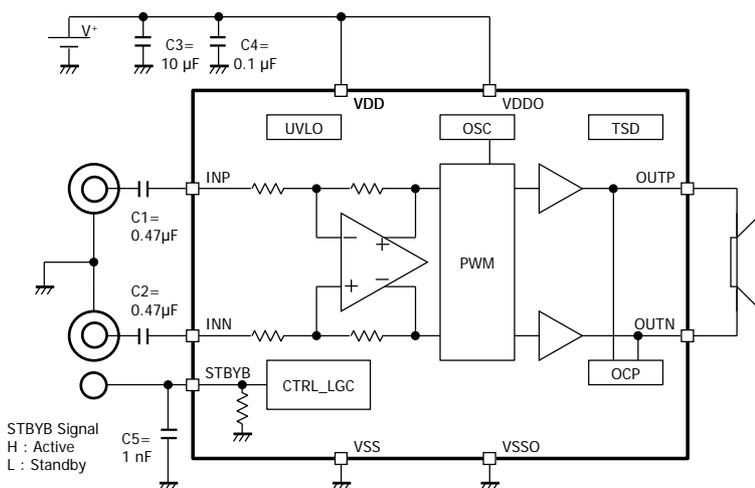
### APPLICATIONS

- Security equipment
- Portable Equipment
- Portable Audio

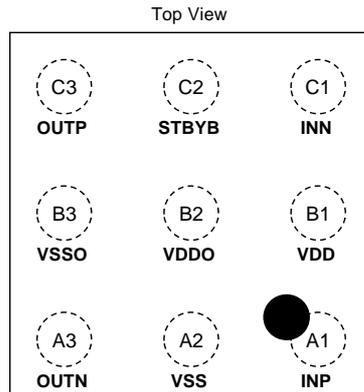
### MONAURAL POWER AMPLIFIER VARIATION

PRODUCT NAME	Description
NJU72060	0.5W Class-AB Power Amp
NJU7089	1.2W 1.8V Class-AB Power Amp
NJU8759AGM1	3.0W Filter Less Class-D Amplifier with HSOP8

### APPLICATION CIRCUIT



## ■ PIN CONFIGURATIONS



PIN No.	SYMBOL	FUNCTION
A1	INP	Positive input
A2	VSS	Analog GND
A3	OUTN	Negative output
B1	VDD	Power supply
B2	VDDO	Output power supply
B3	VSSO	Power GND
C1	INN	Negative input
C2	STBYB	Standby control
C3	OUTP	Positive output

## ■ PRODUCT NAME INFORMATION



## ■ ORDERING INFORMATION

PRODUCT NAME	PACKAGE	RoHS	HALOGEN-FREE	TERMINAL FINISH	MARKING	WEIGHT (mg)	MOQ (pcs)
NJU8759WLC1	WCSP9	Yes	Yes	SnAgCu	8759	1.9	3000

## ■ ABSOLUTE MAXIMUM RATINGS

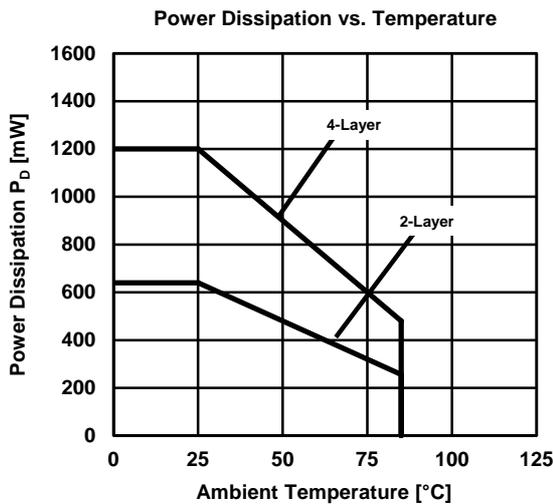
PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	$V^+ - V^-$	7	V
Input Voltage	$V_{IN}$	0 to $V^+$	V
Load Resistance	$R_L$	$\geq 3.4\Omega$	$\Omega$
Power Dissipation ( $T_a=25^\circ\text{C}$ ) WCSP9	$P_D$	2-Layer / 4-Layer <sup>(1)</sup> 640 / 1200	mW
Storage Temperature Range	$T_{stg}$	-40 to 125	$^\circ\text{C}$
Maximum Junction Temperature	$T_{jmax}$	125	$^\circ\text{C}$

## ■ THERMAL CHARACTERISTICS

PACKAGE	SYMBOL	VALUE	UNIT
Junction-to-Ambient Thermal Resistance WCSP9	$\Theta_{ja}$	2-Layer / 4-Layer <sup>(1)</sup> 156.6 / 83.4	$^\circ\text{C/W}$

(1) 2-layer: Mounted on glass epoxy board. (101.5×114.5×1.6mm: based on EIA/JEDEC standard, 2-layer FR-4, with Exposed Pad)  
 4-layer: Mounted on glass epoxy board. (101.5×114.5×1.6mm: based on EIA/JEDEC standard, 4-layer FR-4, with Exposed Pad)  
 \*For 4Layers: Applying 99.5×99.5mm inner Cu area and a thermal via hole to a board based on JEDEC standard JESD51-5)

## ■ POWER DISSIPATION vs. AMBIENT TEMPERATURE



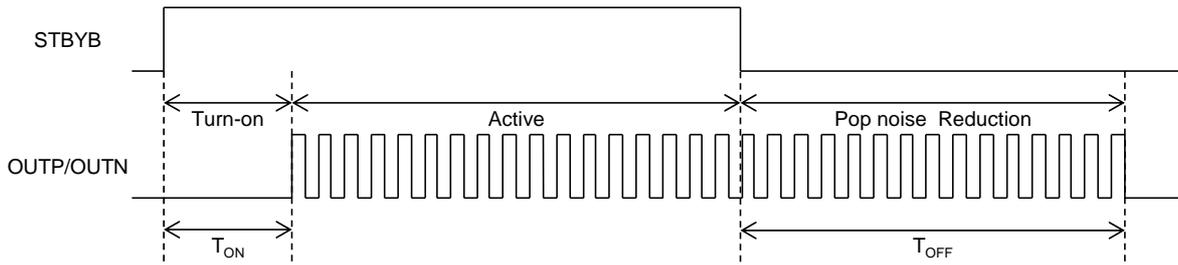
## ■ RECOMMENDED OPERATING CONDITIONS ( $V_{DD}=V_{DDO}=V^+$ , $V_{SS}=V_{SSO}=GND$ )

PARAMETER	SYMBOL	CONDITIONS	VALUE	UNIT
Supply Voltage	$V^+$	$R_L \geq 3.6\Omega$	1.8 to 5.5	V
		$R_L \geq 3.4\Omega$	2.0 to 5.5	V
Operating Temperature Range	$T_{opr}$	$R_L \geq 3.6\Omega$	-40 to 85	$^\circ\text{C}$
		$R_L \geq 3.4\Omega$	-40 to 80	$^\circ\text{C}$

■ **ELECTRICAL CHARACTERISTICS** ( $V^+=3.6V$ ,  $T_a=25^\circ C$ , unless otherwise noted.)

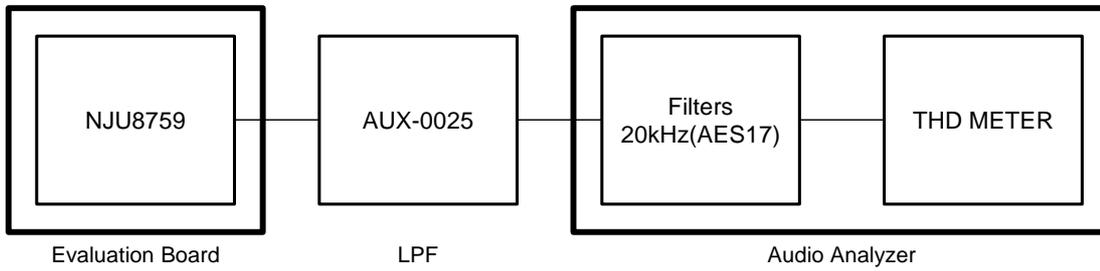
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>DC CHARACTERISTICS</b>						
Standby Current	$I_{ST}$		-	-	1.0	$\mu A$
Supply Current	$I_Q$		-	2.7	-	mA
UVLO Detect Voltage	$V_{DDDET}$		1.1	1.4	1.7	V
UVLO Hysteresis Voltage	$V_{DDHYS}$		-	0.05	-	V
Digital Input Voltage	$V_{IH}$		1.5	-	VDD	V
	$V_{IL}$		0	-	0.3	V
Pull Down Resistance	$R_{DWN}$	STBYB Terminal	-	100	-	k $\Omega$
Input Resistance	$R_{IN}$	INP, INN Terminal	-	30	-	k $\Omega$
Switching Frequency	$f_{OSC}$		100	250	395	kHz
Turn On Time	$T_{ON}$		10	16	40	ms
Turn Off Time	$T_{OFF}$		10	16	40	ms
Voltage Gain	$A_V$		17.5	18	18.5	dB
Output Offset Voltage at Turn-ON / Turn-OFF	$V_{OS}$		-20	-	20	mV
<b>AC CHARACTERISTICS</b> ( $R_L=8\Omega$ , $BW=20Hz$ to $20kHz$ , $f_{in}=1kHz$ , unless otherwise noted.)						
Output Power	$P_o$	$V^+=5V$ , THD+N=10%, $R_L=8\Omega$	-	1.7	-	W
		$V^+=5V$ , THD+N=10%, $R_L=4\Omega$	-	3.0	-	W
Output Power Efficiency	$\eta$	$V^+=5V$ , THD+N=10%, $R_L=8\Omega+33\mu H$	-	93	-	%
Total Harmonic Distortion + Noise	THD+N	$P_o=0.5W$	-	0.05	-	%
		$V^+=5V$ , $P_o=1.0W$	-	0.035	-	%
Supply Voltage Rejection Ratio	PSRR	$f_{in}=217Hz$ , ripple=200mV <sub>PP</sub>	-	-55	-	dB
Common-Mode Rejection Ratio	CMRR	$f_{in}=217Hz$ , $V_{inc}=1V_{PP}$	-	-55	-	dB
Output Voltage Noise	$V_{NO}$	A-weighting	-	62	-	$\mu V$

## ■ TURN ON / TURN OFF SEQUENCE

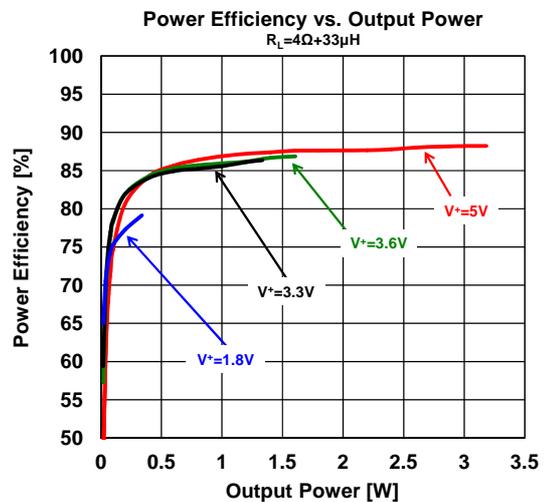
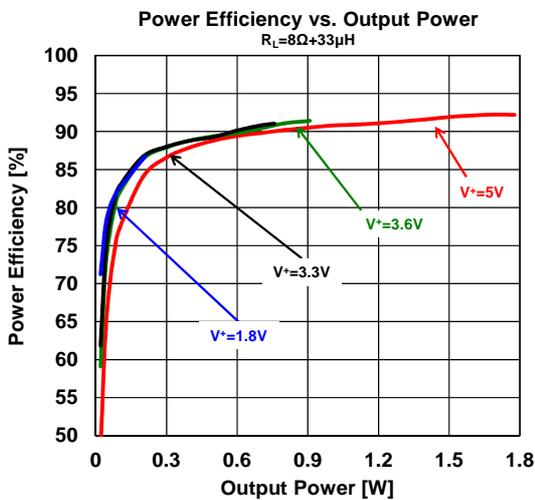
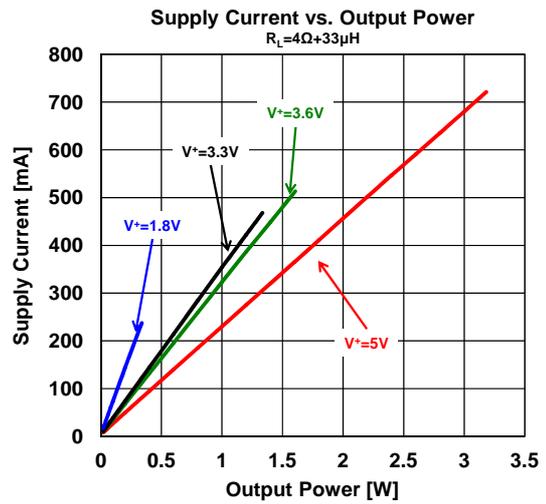
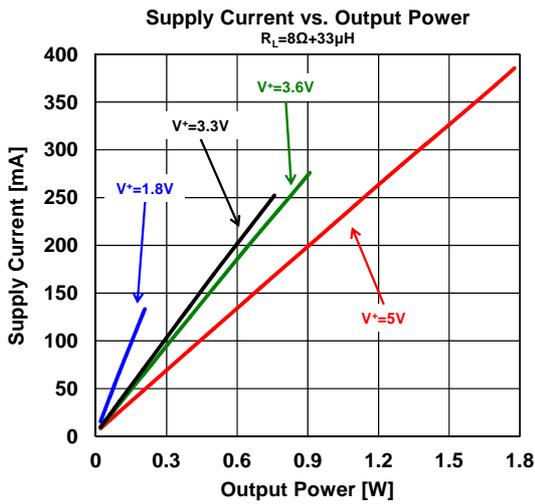
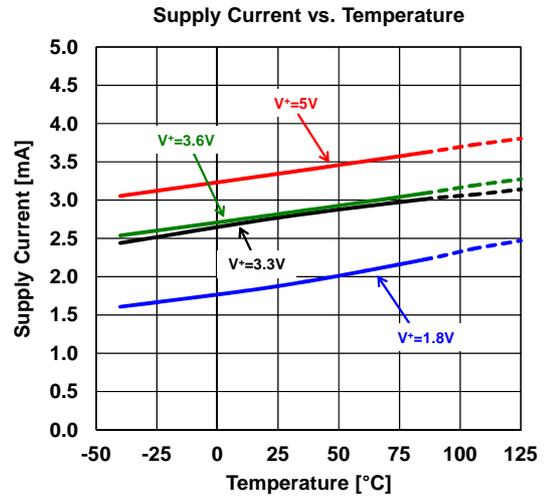
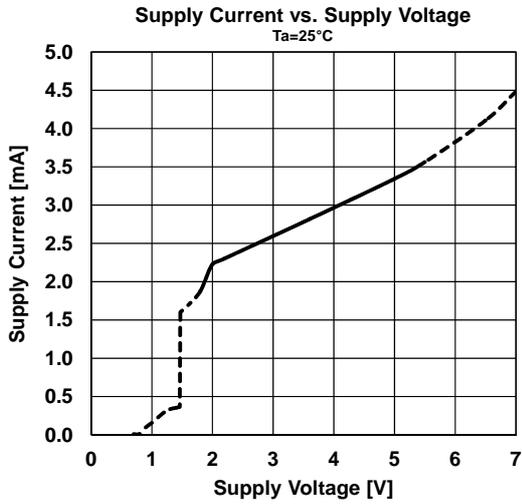


When STBYB is set to "H" in the TOFF, it shifts to Active mode immediately.

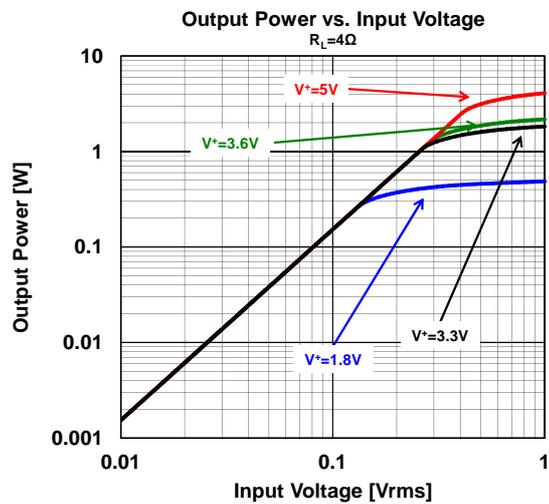
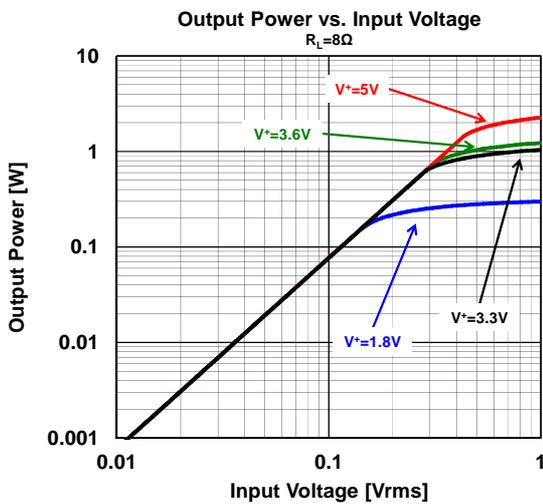
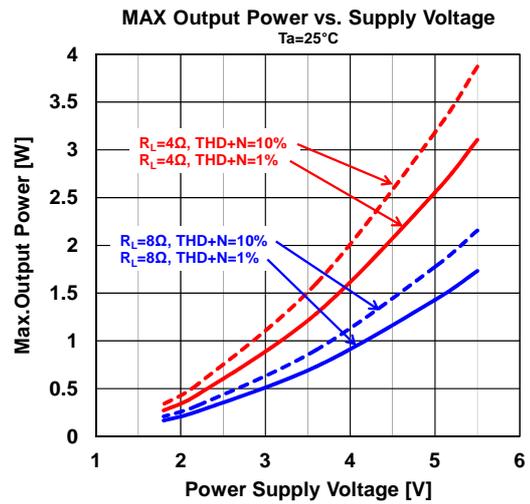
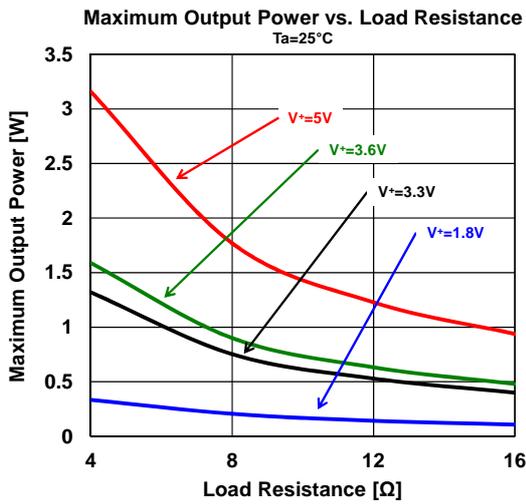
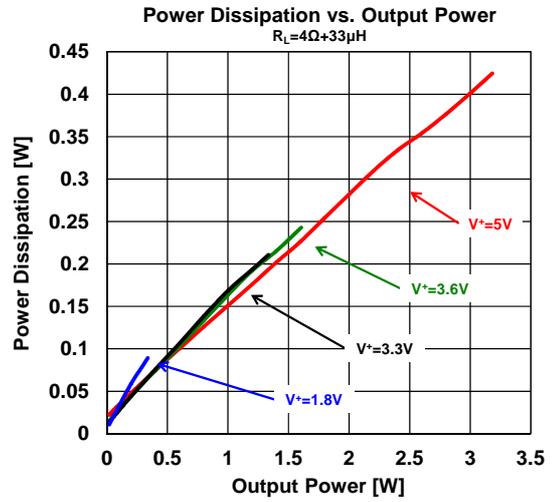
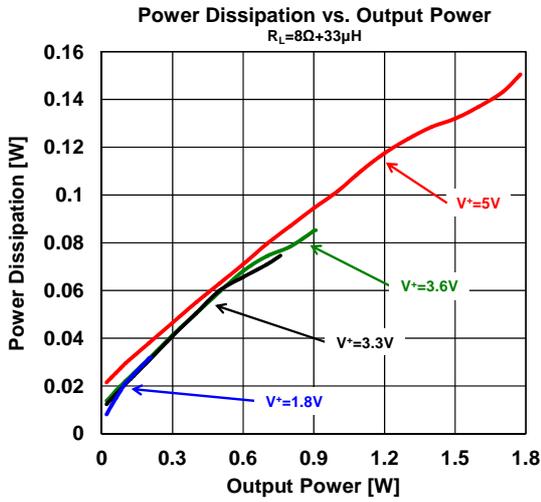
## ■ TEST SYSTEM OF THE OUTPUT THD+N



## ■ TYPICAL CHARACTERISTICS

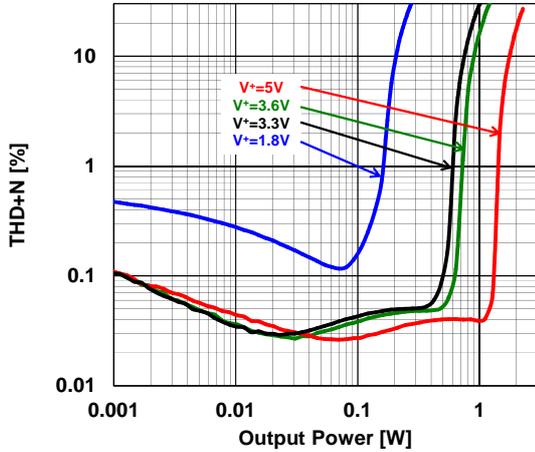


## ■ TYPICAL CHARACTERISTICS

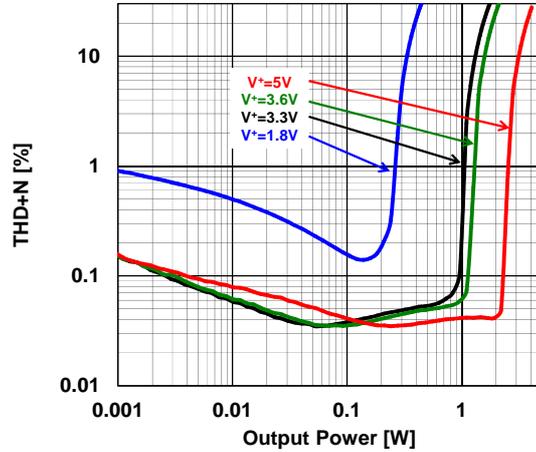


## ■ TYPICAL CHARACTERISTICS

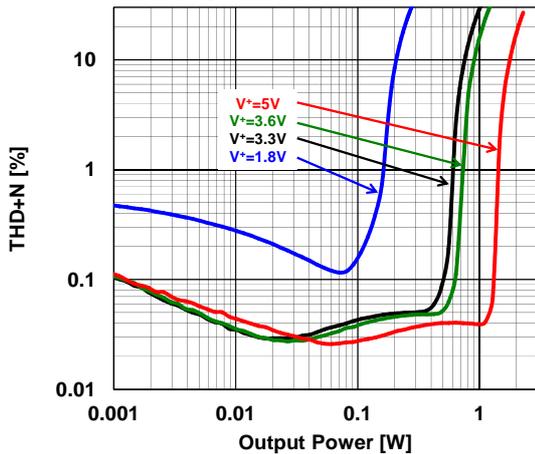
**THD+N vs. Output Power**  
 $R_L=8\Omega$ , Differential Input,  $T_a=25^\circ\text{C}$



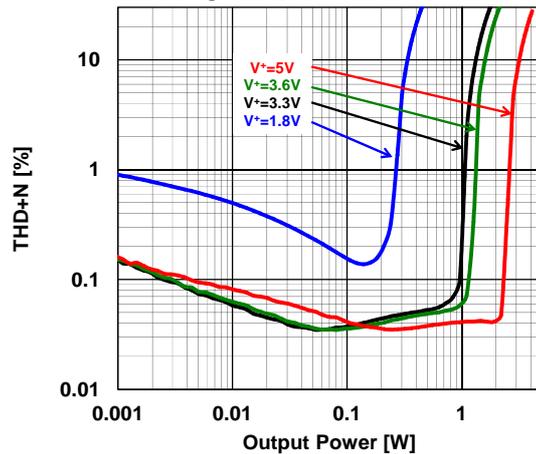
**THD+N vs. Output Power**  
 $R_L=4\Omega$ , Differential Input,  $T_a=25^\circ\text{C}$



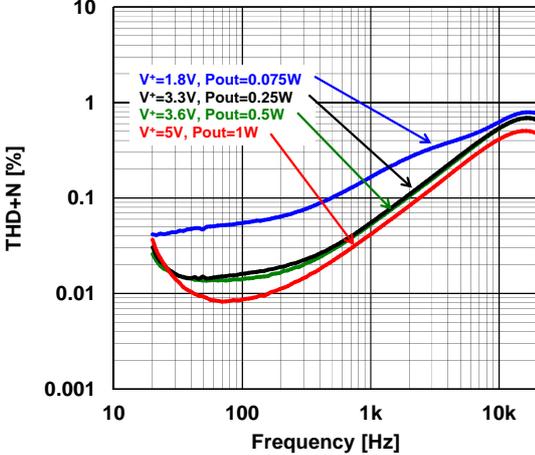
**THD+N vs. Output Power**  
 $R_L=8\Omega$ , Single-ended Input,  $T_a=25^\circ\text{C}$



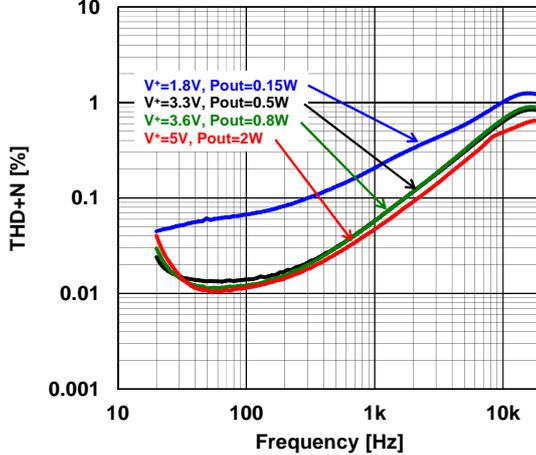
**THD+N vs. Output Power**  
 $R_L=4\Omega$ , Single-ended Input,  $T_a=25^\circ\text{C}$



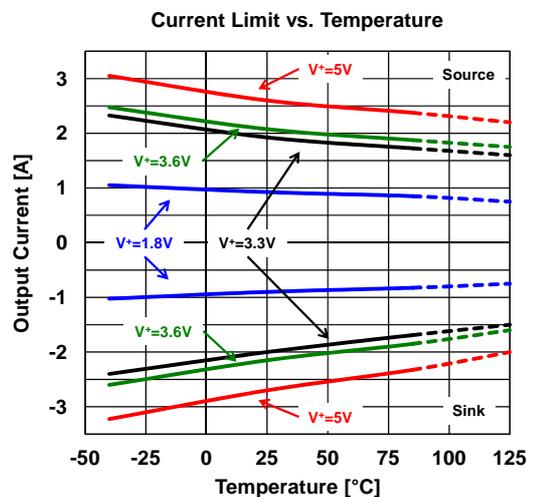
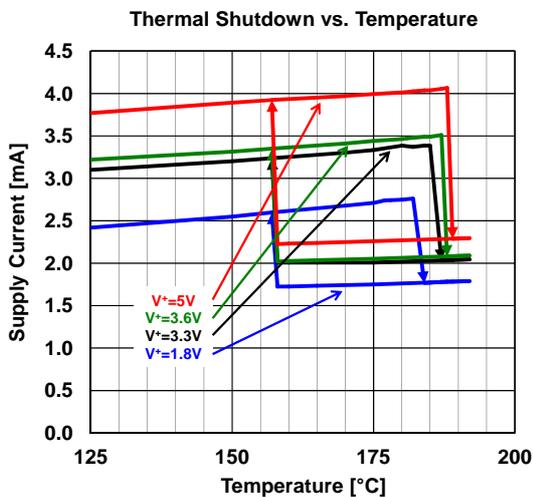
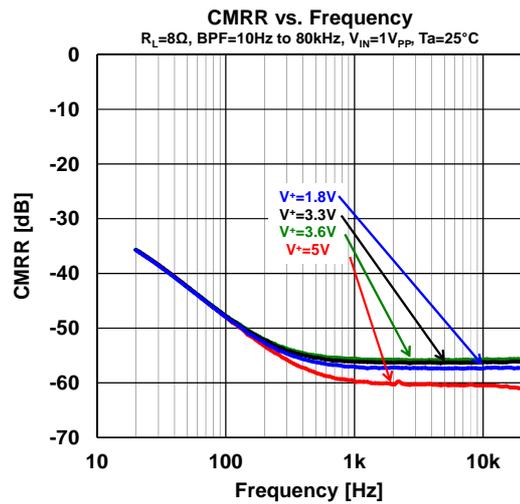
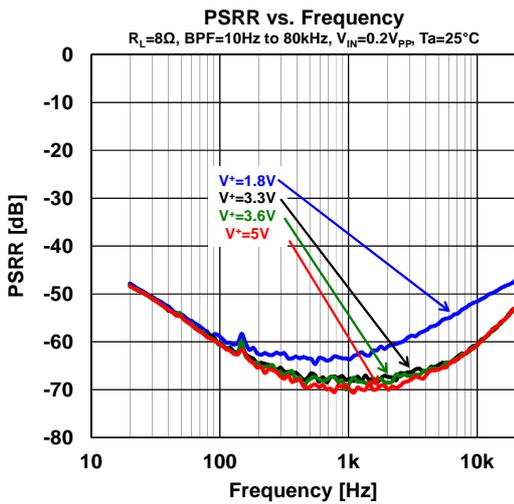
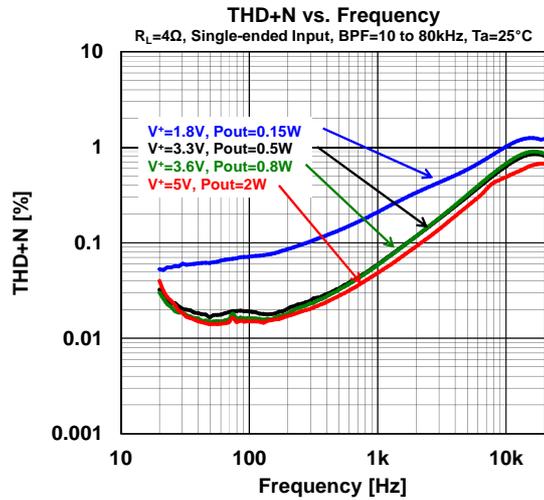
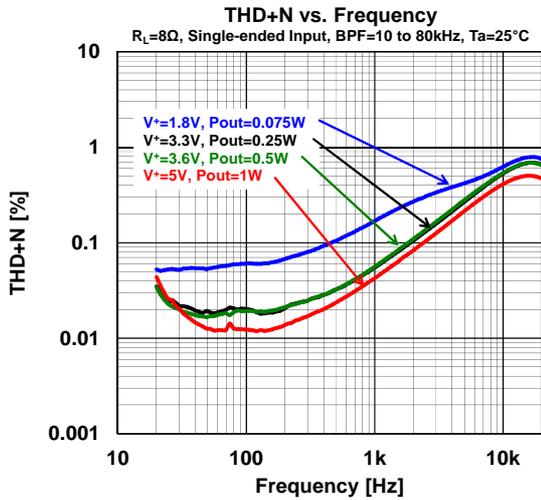
**THD+N vs. Frequency**  
 $R_L=8\Omega$ , Differential Input, BPF=10 to 80kHz,  $T_a=25^\circ\text{C}$



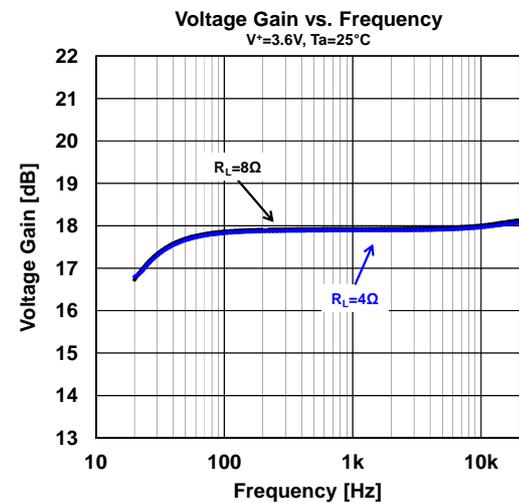
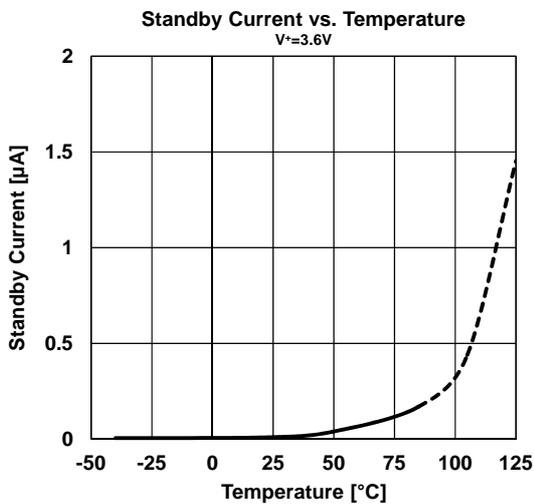
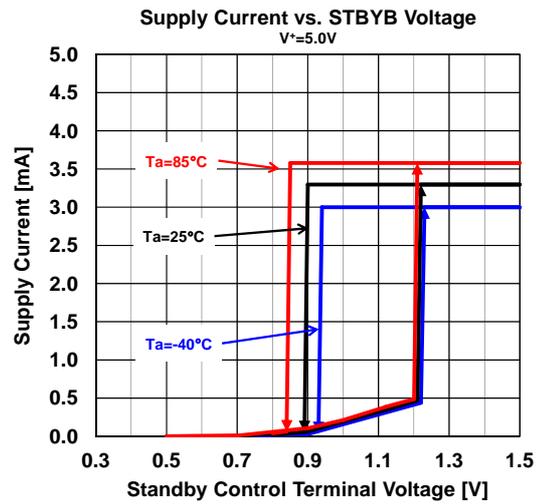
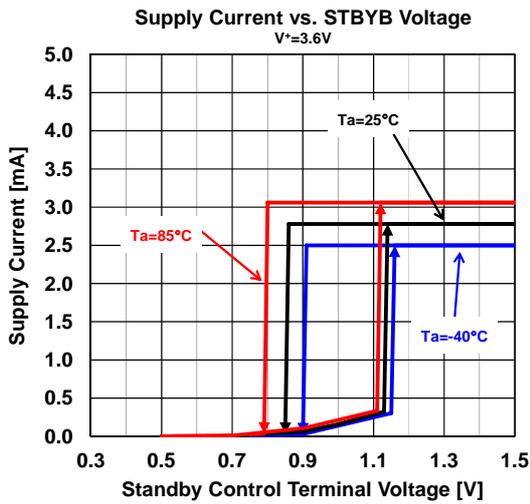
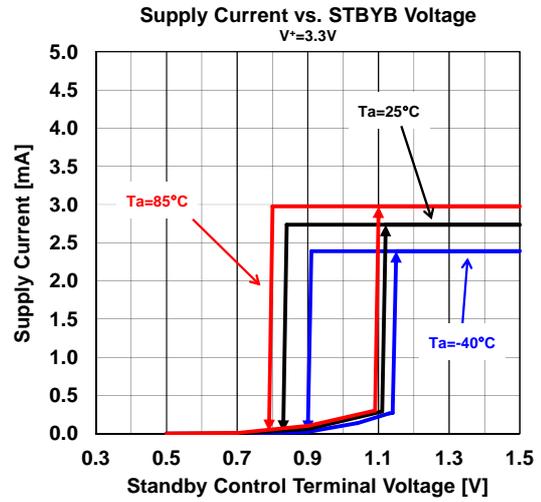
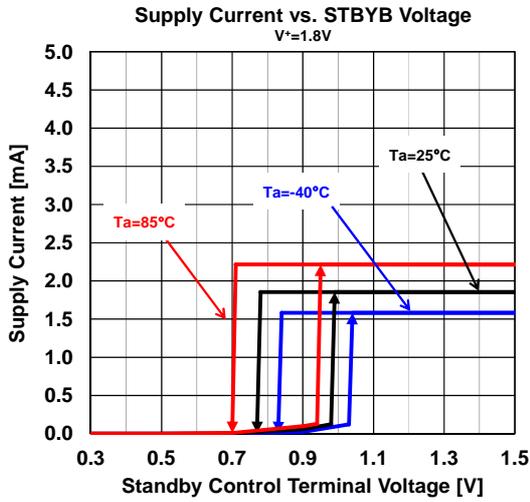
**THD+N vs. Frequency**  
 $R_L=4\Omega$ , Differential Input, BPF=10 to 80kHz,  $T_a=25^\circ\text{C}$



## ■ TYPICAL CHARACTERISTICS



## ■ TYPICAL CHARACTERISTICS



## ■ APPLICATION NOTE

The NJU8759 is an analog signal input monaural filterless class-D power amplifier. Operating voltage from 1.8V to 5.5V single supply can be used with 2-cell batteries. NJU8759 features Class-D operation with high output capability, is 1.7W output (8Ω load) and 3.0W output (4Ω load). The BTL output configuration can reduce the coupling capacitor. Furthermore, the output LC filterless architecture reduces external parts and PCB size.

### 1. OPERATING PRINCIPLE

Figure 1-1 shows the NJU8759 block diagram. The NJU8759 consists of a Class-D Amplifier, an Under Voltage Lockout, a Thermal Shut Down and Output Short Protections.

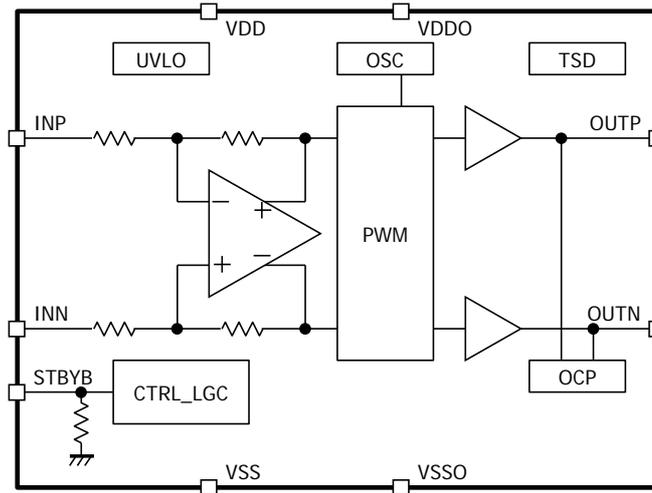


Figure 1-1 the NJU8759 block diagram

## 2. FUNCTIONAL DESCRIPTION

### 2.1. Audio Signals

Differential analog signals are input into INP and INN as Figure 2-1 (a). The voltage gain is shown by

$$A_V = \frac{V_{OUTP} - V_{OUTN}}{V_{INP} - V_{INN}} = 18\text{dB}$$

In case of a single-ended input signal application, an analog signal is input into INP as Figure 2-1 (b).

Some troubles may be caused by the input signal voltage over power supply voltage. So design the input signal voltage under 600mVrms. Also, same troubles may be caused in case of floating input pins. For preventing floating input pins, design former audio IC active mode before releasing NJU8759 stand-by mode, or connect 1 MΩ pull-down resistors shown as Figure 2-2.

PWM signals are output from OUTP and OUTN. Connect a dynamic speaker between OUTP and OUTN. The NJU8759 does not require OUTPUT LC filters which a traditional class-D amplifier needed. The output power is shown below.

$$P_{OUT} = \frac{[A_V(V_{INP} - V_{INN})]^2}{R_L} \text{ [W]}$$

As mentioned below, the NJU8759 operates cancelling output offset voltage during turn-on and turn-off time. In case of an application that audio signals are input during turn-on and turn-off time, evaluate a pop-noise adequately.

The input capacitors and input resistors set a high-pass filter. Its corner frequency is given by

$$f_c = \frac{1}{2\pi \times 30\text{k}\Omega(\text{typ.}) \times C1}$$

The recommended capacitor value is under 0.47μF.

## APPLICATION NOTE

### 2.1. Audio Signals (Continued)

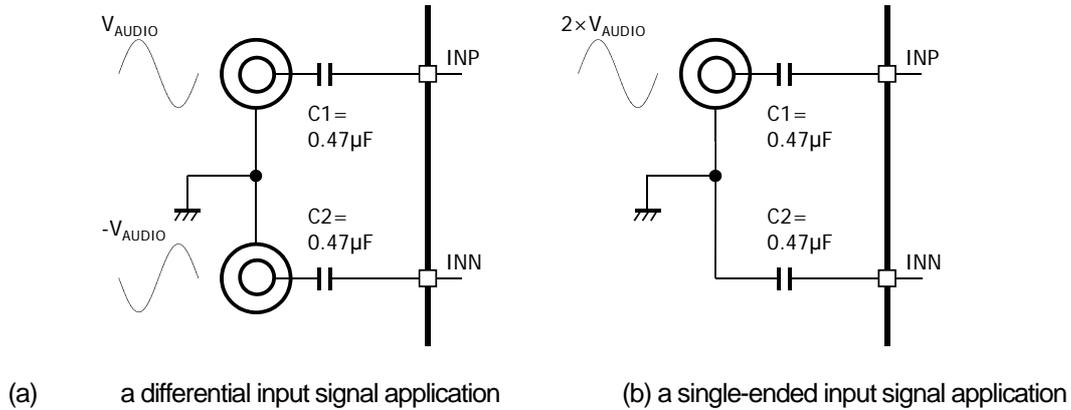


Figure 2-1 How to input audio signals

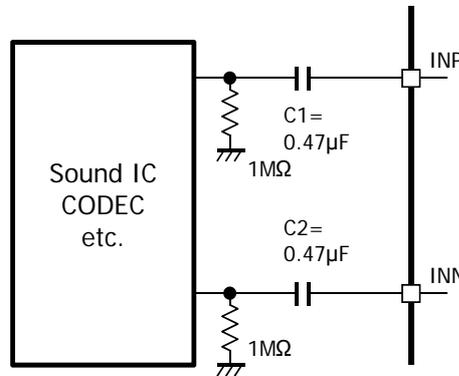


Figure 2-2 How to prevent floating input pins

### 2.2. Thermal Design

The output power is restricted by maximum rating.

Maximum package power dissipation at any ambient temperature is given by

$$P_{\text{DMAX}} = \frac{125[^\circ\text{C}] - T_a[^\circ\text{C}]}{\theta_{ja}[^\circ\text{C} / \text{W}]}$$

Where  $P_{\text{DMAX}}$ : maximum power dissipation [W],  $T_a$ : ambient temperature [ $^\circ\text{C}$ ],  $\theta_{ja}$ : thermal resistance [ $^\circ\text{C}/\text{W}$ ]

The IC power dissipation referred to figure 2-3 is a difference between supply power and output power shown by

$$P_D = (V^+ [\text{V}] \times I_{\text{supply}} [\text{A}]) - P_{\text{OUT}} [\text{W}]$$

Design so that the IC power dissipation  $P_D$  does not exceed the maximum package power dissipation  $P_{\text{DMAX}}$ .

For the power dissipation and thermal resistance of each package, refer to the absolute maximum ratings and thermal resistance in the data sheet.

■ APPLICATION NOTE

2.2. Thermal Design (Continued)

Ex.)  $T_a=50^{\circ}\text{C}$ ,  $V^+=5\text{V}$ ,  $I_{\text{SUPPLY}}=560\text{mA}$ ,  $P_{\text{OUT}}=2.5\text{W}$ , WCSP9 package, 4-layer PCB

$$\text{Power dissipation } P_D = (5[\text{V}] \times 560[\text{mA}]) - 2.5[\text{W}] = 300[\text{mW}]$$

Maximum package power dissipation  $P_{\text{DMAX}}$  at  $T_a=50^{\circ}\text{C}$

$$P_{\text{DMAX}} = \frac{125[^{\circ}\text{C}] - 50[^{\circ}\text{C}]}{83.4[^{\circ}\text{C} / \text{W}]} = 900[\text{mW}]$$

The power dissipation  $P_D$  is within the maximum package power dissipation  $P_{\text{DMAX}}$ .

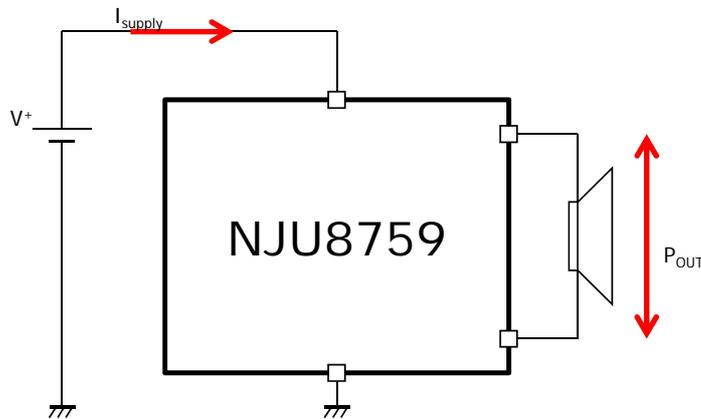


Figure 2-3 a power dissipation model

## ■ APPLICATION NOTE

### 2.3. Stand-by Control

Input the stand-by control signal into "STBYB" terminal with 100kΩ pull down resistor.

The NJU8759 operates if "STBYB" voltage over H level digital voltage is applied and after turn-on time (16ms typ.), an audio signal is output.

The NJU8759 shuts down if "STBYB" voltage under L level digital voltage is applied and after turn-off time (16ms typ.), it goes to the stand-by mode.

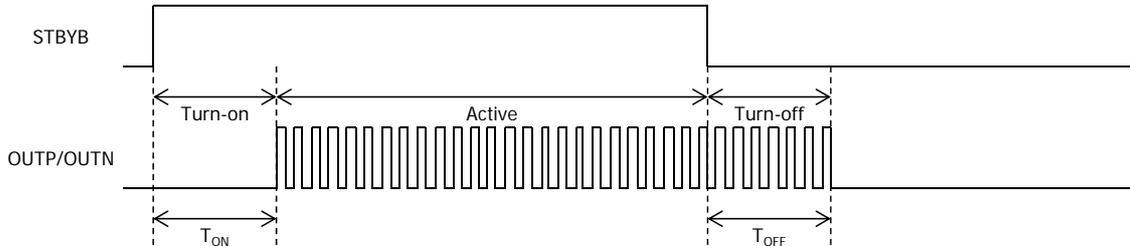


Figure 2-4 Timing chart

### 2.4. Under Voltage Lock Out

When the power-supply voltage drops down under UVLO detecting voltage, OUP and OUTN become high impedance. When the power-supply voltage increases to over UVLO detecting voltage summing hysteresis voltage, it restarts after the turn-on time.

### 2.5. Short Protection

The short-circuit protection circuit operates at the condition of the following.

- Short between OUP and OUTN
- GND fault of OUP terminal
- GND fault of OUTN terminal
- V<sup>+</sup> fault of OUP terminal
- V<sup>+</sup> fault of OUTN terminal

When short-circuit protection circuit operates, the OUP and OUTN become "high impedance". It restarts by turn-on sequence.

The detectable current and the period for the protection depend on the power supply voltage and temperature. And the short protector is not effective for a long term short-circuit current but for an instantaneous accident.

Continuous high current may cause permanent damage to the NJU8759.

### 2.6. Thermal Shut Downs

When IC junction temperature is higher than detecting temperature, the OUP and OUTN become high impedance. It restarts if IC junction temperature is lower than releasing temperature.

■ APPLICATION NOTE

2.7. EMI Restriction

If it is necessary to restrict EMI, design the short traces from the amplifier to the speaker. If you need more restriction, design the short traces with ferrite beads shown as Figure 2-5

Figure 2-6 is the measurement result on equivalent VCCI CLASS-B 3m with 100mm traces from the amplifier to the speaker.

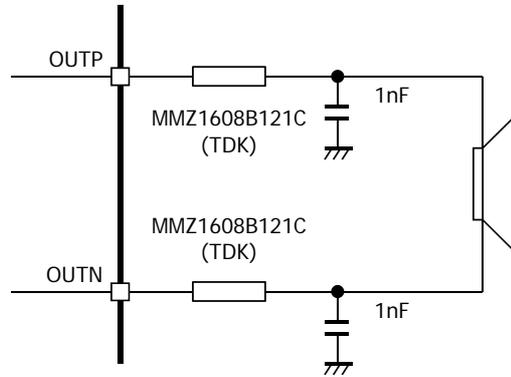
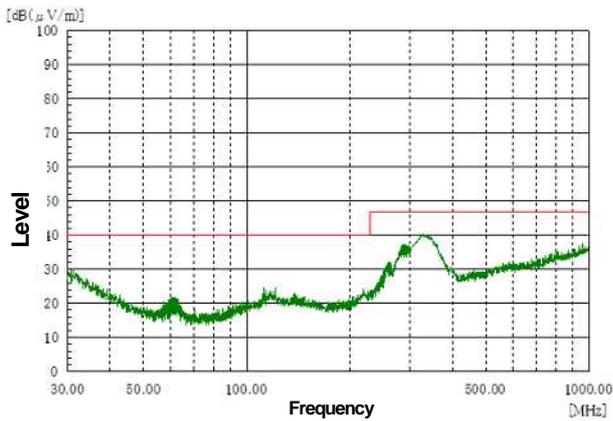
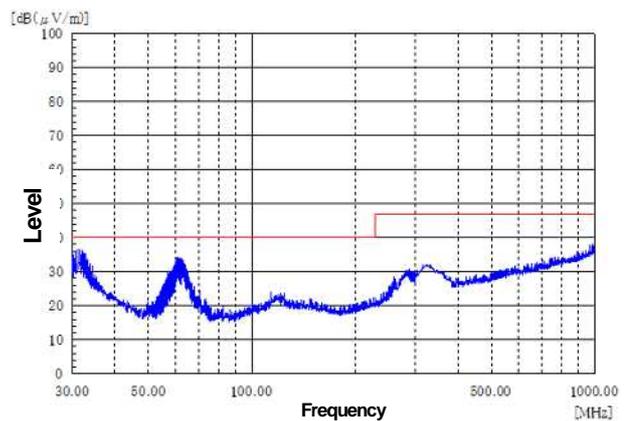


Figure 2-5 an EMI restriction model



(a) horizontal



(b) vertical

Figure 2-6 EMI result on equivalent VCCI CLASS-B 3m

■ APPLICATION NOTE

2.8. PCB Layout

Figure 2-7 shows an example for 4-layer PCB Layout around the NJU8759.

For VDDO, VSSO, OUTP, and OUTN through which a large current flows, lay out with the maximum width allowed by the wiring rules. The power supply of NJU8759 must operate stably against the sink or source current that is generated by the audio signal and the output stage. Chip ceramic capacitors are recommended for bypass capacitors between V<sup>+</sup> and GND. It is recommended the 0.1μF capacitor sets near VDD, VDDO, VSS and VSSO pin for the restricting ripple.

If the standby control signal is noisy, the standby mode may not be controlled properly. In such cases, a capacitor of 1nF or more placed near the IC to eliminate then noise of standby control signal.

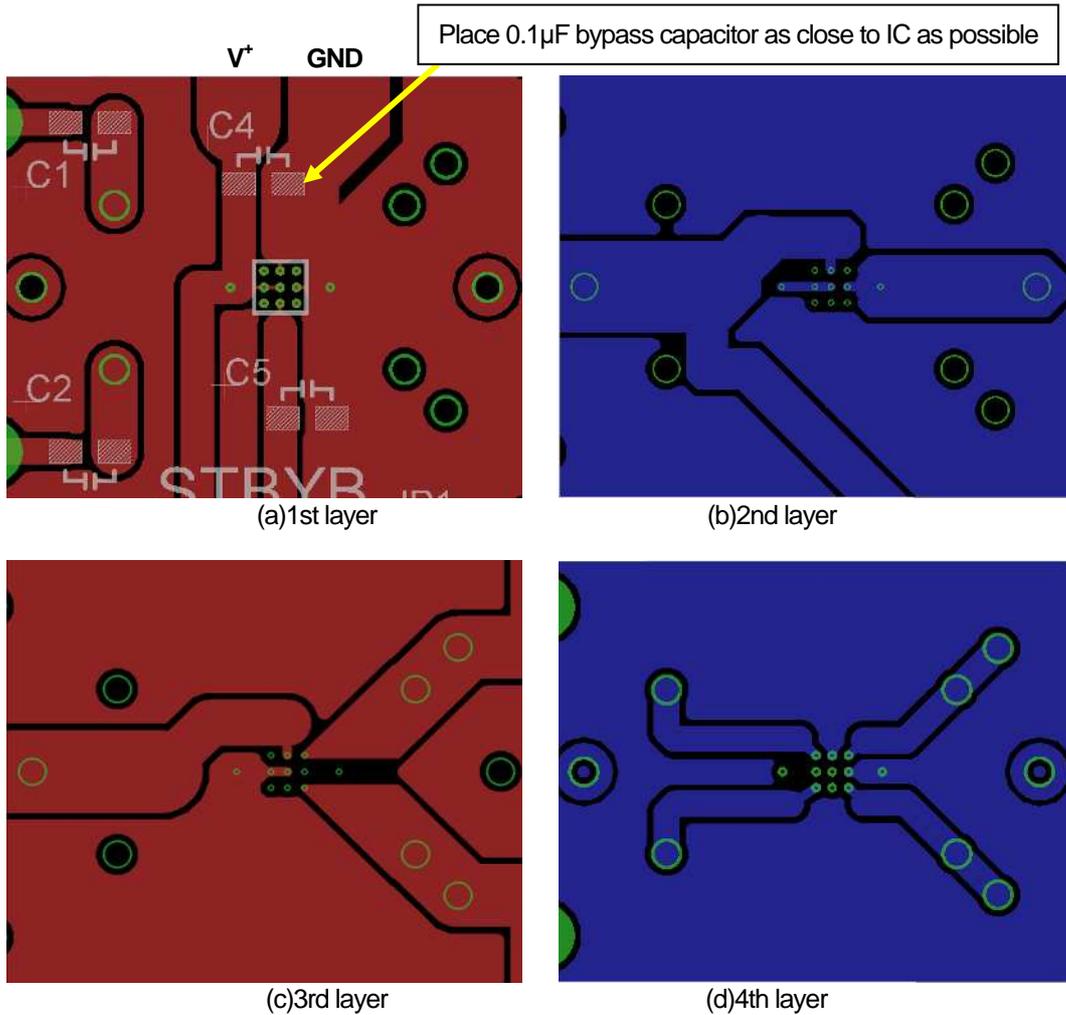
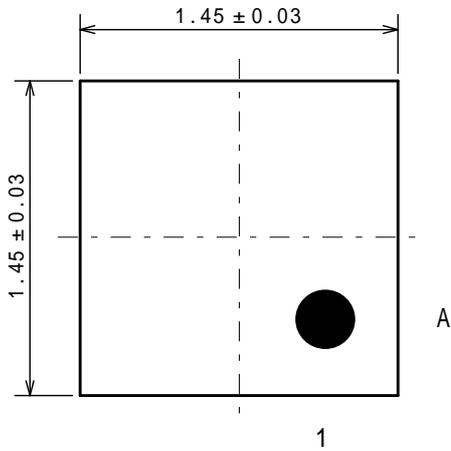


Figure 2-7 an example for 4 layer PCB Layout around the NJU8759

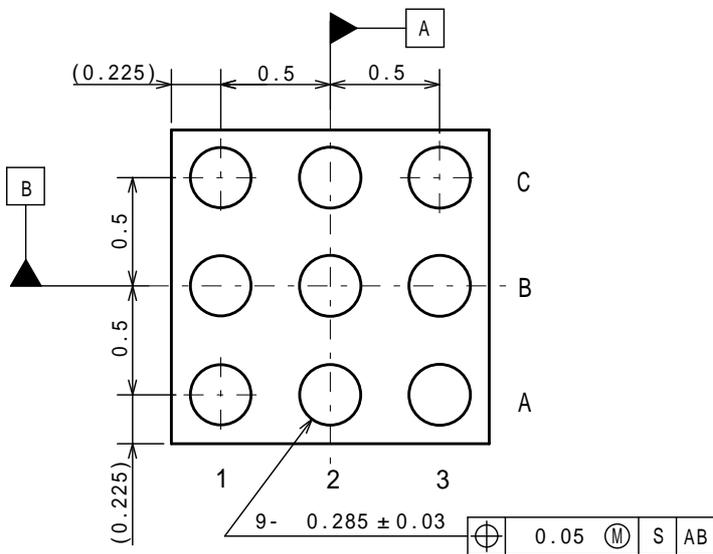
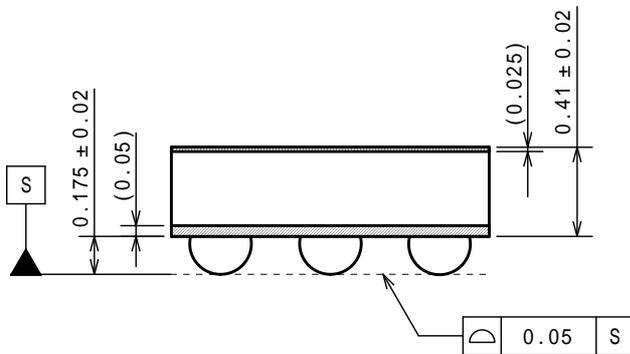
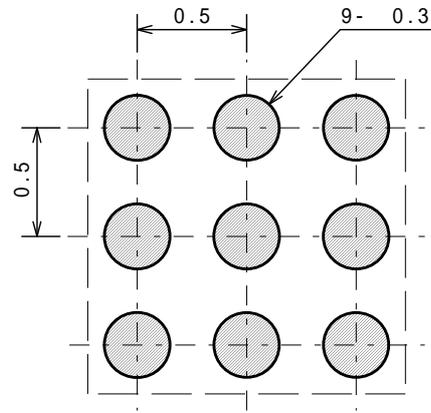
## WCSP9

Unit: mm

### ■ PACKAGE DIMENSIONS



### ■ EXAMPLE OF SOLDER PADS DIMENSIONS

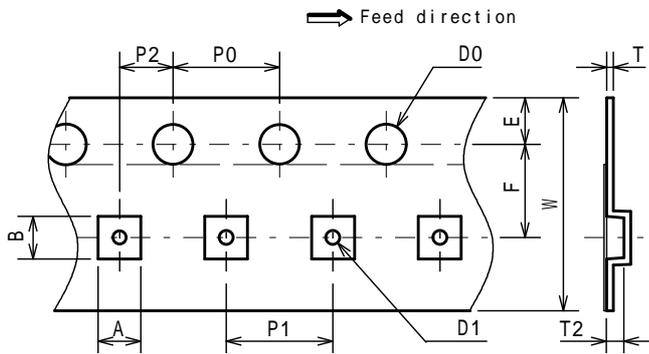


## WCSP9

### PACKING SPEC

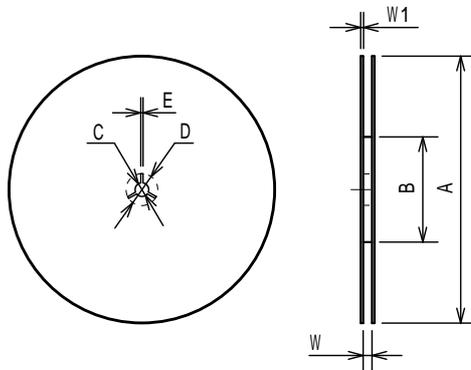
Unit: mm

#### TAPING DIMENSIONS



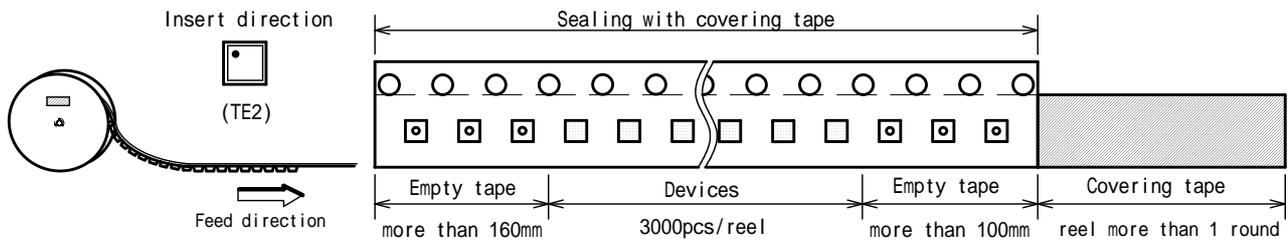
SYMBOL	DIMENSION	REMARKS
A	1.55 ± 0.05	BOTTOM DIMENSION
B	1.55 ± 0.05	BOTTOM DIMENSION
D0	1.5 <sup>+0.1</sup> <sub>0</sub>	
D1	0.5 ± 0.1	
E	1.75 ± 0.1	
F	3.5 ± 0.05	
P0	4.0 ± 0.1	
P1	4.0 ± 0.1	
P2	2.0 ± 0.05	
T	0.25 ± 0.05	
T2	0.7 ± 0.05	
W	8.0 <sup>+0.3</sup> <sub>-0.1</sub>	

#### REEL DIMENSIONS

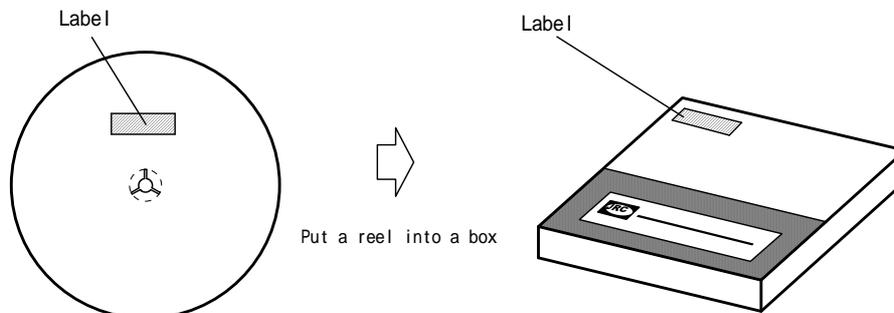


SYMBOL	DIMENSION
A	180 <sup>0</sup> <sub>-1.5</sub>
B	60 <sup>+1</sup> <sub>0</sub>
C	13 ± 0.2
D	21 ± 0.8
E	2 ± 0.5
W	9 <sup>+1</sup> <sub>0</sub>
W1	1.2 ± 0.2

#### TAPING STATE

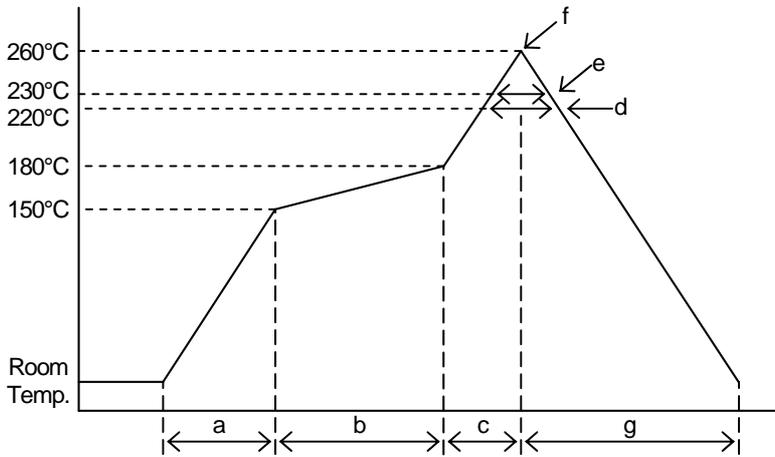


#### PACKING STATE



## ■ RECOMMENDED MOUNTING METHOD

### INFRARED REFLOW SOLDERING PROFILE



a	Temperature ramping rate	1 to 4°C/s
b	Pre-heating temperature	150 to 180°C
	Pre-heating time	60 to 120s
c	Temperature ramp rate	1 to 4°C/s
d	220°C or higher time	shorter than 60s
e	230°C or higher time	shorter than 40s
f	Peak temperature	lower than 260°C
g	Temperature ramping rate	1 to 6°C/s

The temperature indicates at the surface of mold package.

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